Semiconductors
High-reliability discrete products and engineering services since 1977

1N4148UR

## GLASS SWITCHING DIODE

## FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.
- Metallurgically bonded.
- Hermetically sealed.
- Double plug construction.

MAXIMUM RATINGS @ $25^{\circ} \mathrm{C}$

| Ratings | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Junction and storage temperature range | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | -65 to 175 | ${ }^{\circ} \mathrm{C}$ |
| Thermal resistance, junction to ambient ${ }^{(1)}$ | $\mathrm{R}_{\text {өJA }}$ | 325 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal resistance, junction to endcap ${ }^{(2)}$ | $\mathrm{R}_{\text {өJEC }}$ | 100 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Maximum breakdown voltage | $\mathrm{V}_{\text {(BR) }}$ | 100 | V |
| Working peak reverse voltage | $\mathrm{V}_{\text {RWM }}$ | 75 | V |
| Average rectified current @ $\mathrm{T}_{\mathrm{A}}=75^{\circ} \mathrm{C}{ }^{(3)}$ | $\mathrm{l}_{0}$ | 200 | mA |
| Non-repetitive sinusoidal surge current (tp = 8.3ms) | $\mathrm{I}_{\text {FSM }}$ | 2 | A(pk) |

Note 1: $\mathrm{T}_{\mathrm{A}}=75^{\circ} \mathrm{C}$ on printed circuit board (PCB), PCB $=$ FR4-0.0625" 1-layer 1-oz Cu, horizontal, in still air; pads $=0.061^{\prime \prime} \times 0.105^{\prime \prime}$; ReJA with a defined PCB thermal resistance condition included, is measured at $\mathrm{I}_{0}=200 \mathrm{~mA} \mathrm{dc}$.
Note 2: See Figure 2
Note 3: See Figure 1
ELECTRICAL CHARACTERISTICS @ $25^{\circ} \mathrm{C}$ unless otherwise noted

| Forward voltage | Forward voltage | Reverse recovery time | Forward recovery time | Reverse current | Reverse current | Reverse current | Reverse current | Capacitance | Capacitance |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{gathered} V_{F 1} @ I_{F}= \\ 10 \mathrm{~mA} \end{gathered}$ | $\begin{gathered} \mathrm{V}_{\mathrm{F} 2} @ \mathrm{I}_{\mathrm{F}}= \\ 100 \mathrm{~mA} \end{gathered}$ | $\mathrm{trr}^{(1)}$ | $\mathrm{Tfr}^{(2)}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{R} 1} @ \\ & 20 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{R} 2} @ \\ & 75 \mathrm{~V} \end{aligned}$ | $\mathrm{I}_{\mathrm{R} 3} @$ $20 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=$ <br> $150^{\circ} \mathrm{C}$ | $\stackrel{\mathrm{I}_{\mathrm{R} 4} @}{\mathrm{C}_{\mathrm{A}}}=$ <br> $75 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=$ <br> $150^{\circ} \mathrm{C}$ | C ${ }^{(3)}$ | $\mathbf{C l}^{(4)}$ |
| V | V | ns | ns | nA | $\mu \mathrm{A}$ | $\mu \mathrm{A}$ | $\mu \mathrm{A}$ | pF | pF |
| 0.8 | 1.2 | 5 | 20 | 25 | 0.5 | 35 | 75 | 4.0 | 2.8 |

[^0]Note 3: $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{SIG}}=50 \mathrm{mV}$ ( pk to pk )
Note 4: $\mathrm{V}_{\mathrm{R}}=1.5 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{SIG}}=50 \mathrm{mV}$ (pk tp pk)


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MECHANICAL CHARACTERISTICS

| Case: | SOD-80 (DO-213AA) |
| :--- | :--- |
| Polarity: | Cathode band |
| Lead finish: | Tin/lead or lead free |



|  | SOD-80 |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Inches |  | Millimeters |  |
|  | Min | Max | Min | Max |
| D | 0.055 | 0.067 | 1.397 | 1.702 |
| F | - | 0.022 | - | 0.559 |
| G | 0.130 | 0.146 | 3.302 | 3.708 |
| G1 | 0.100 REF |  | 2.540 REF |  |
| S | 0.001 |  | - | 0.025 |



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FIGURE 1 - Temperature - Current Derating


FIGURE 2 -Thermal Impedance


[^0]:    Note 2: $I_{F}=50 \mathrm{~mA}$

